

Ultra-Fast Recovery Diodes 8A FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-252
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURS860DL
Device marking code			MURS860DL
Repetitive Peak Reverse Voltage	V _{RRM}	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	8
Surge(Non-repetitive) Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	70
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	20.3
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C _j	pF	42

MURS860DL

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=8.0A$ @ $T_j=25^{\circ}C$	-	2.7	3.6
			$I_{FM}=8.0A$ @ $T_j=150^{\circ}C$	-	1.8	2.3
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	μA	$V_{RM}=V_{RRM}$ $T_j=25^{\circ}C$	-	-	10
	I_{RRM2}		$V_{RM}=V_{RRM}$ $T_j=150^{\circ}C$	-	-	100
Reverse Recovery Time	T_{rr}	ns	$I_F=0.5A$ $I_{RM}=1A$ $I_{RR}=0.25A$ $T_j=25^{\circ}C$	-	14	25
			$T_j=25^{\circ}C$		39	
			$T_j=125^{\circ}C$		50	
Peak recovery current	I_{RRM}	A	$T_j=25^{\circ}C$	-	1.7	-
			$T_j=125^{\circ}C$	-	4.55	-
Reverse recovery charge	Q_{rr}	nC	$T_j=25^{\circ}C$	-	34	-
			$T_j=125^{\circ}C$	-	113	-

■Thermal Characteristics ($T_j=25^{\circ}C$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MURS860DL
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}C/W$	5.0
Thermal Resistance	Between junction and Air	$R_{\theta J-A}$	$^{\circ}C/W$	50

■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MURS860DL	Approximate 0.31	2500	2500	25000	Reel

■Characteristics (Typical)

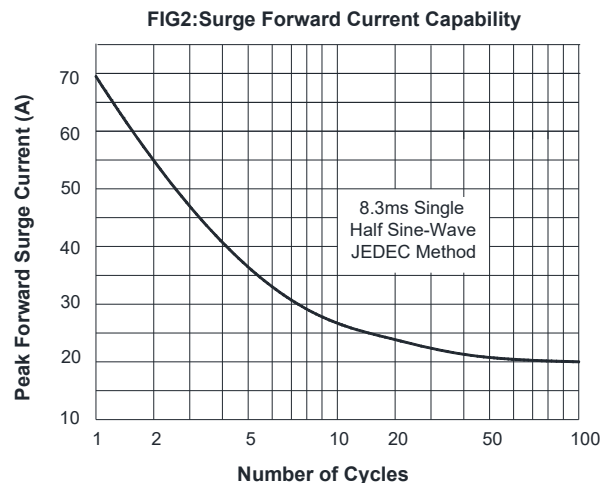
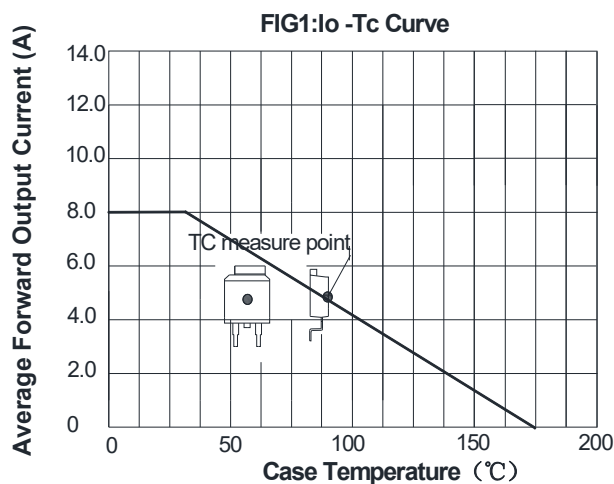


FIG3: Forward Voltage

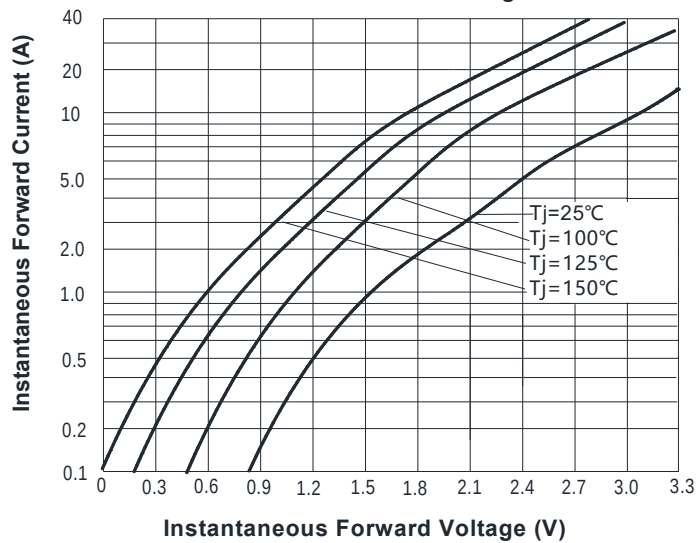
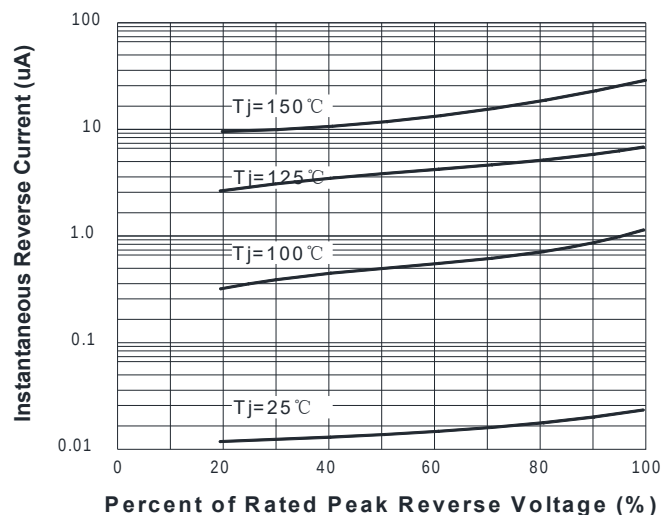
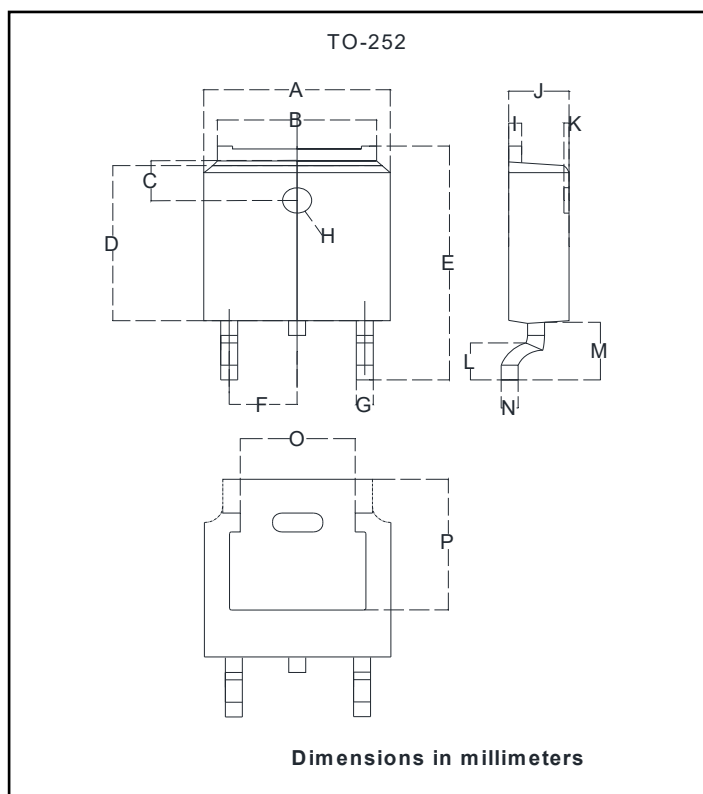


FIG.4: Instantaneous Reverse Characteristics

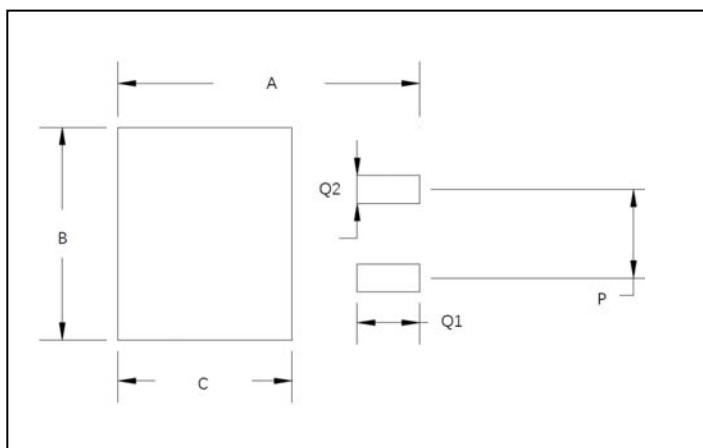


■Outline Dimensions



TO-252		
Dim	Min	Max
A	6.500	6.700
B	5.100	5.460
C	1.400	1.800
D	6.000	6.200
E	10.000	10.400
F	2.166	2.366
G	0.660	0.860
H	Φ1.050	Φ1.350
I	0.460	0.580
J	2.200	2.400
K	0	0.300
L	0.890	2.290
M	2.730	3.080
N	0.430	0.580
O	4.20	4.95
P	5.15	5.45

■ Suggested Pad Layout



Dim	Millimeters
A	11.4
B	6.74
C	6.23
P	4.56
Q1	2.28
Q2	1.52

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